

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 7,399,693 B2
APPLICATION NO. : 10/566170
DATED : July 15, 2008
INVENTOR(S) : Yoshinobu Sekiguchi

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

COLUMN 12:

Line 57, "Al_{0.13}Ga_{0.87} layer 30:" should read -- Al_{0.13}Ga_{0.87} As layer 30: --.

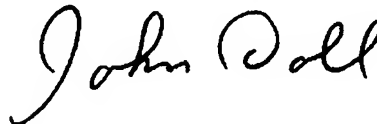
COLUMN 16:

Line 25, "microc-" should read -- micro- --; and

Line 26, "rystalline" should read -- crystalline --.

Signed and Sealed this

Third Day of March, 2009



JOHN DOLL
Acting Director of the United States Patent and Trademark Office